

40 V 600 mA 1ch Constant Current Driver for Automotive LED Lamps

BD18336NUF-M

General Description

The BD18336NUF-M is a constant current driver IC for driving automotive LED lamp, that can withstand up to 40 V. Small-size package is suitable for use in socket LED driver applications.

The BD18336NUF-M offers high reliability with built-in functions for the thermal de-rating function, the LED open detection, the output short circuit protection, the SET pin short circuit protection, the over-voltage mute function, the current bypass function at reduced-voltage, the output for fault flag function and the input for output current OFF control signal.

Key Specifications

- Input Voltage Range: 5.5 V to 20 V
- Output Current Accuracy: ±5 %
- Maximum Output Current: 400 mA (DC)
600 mA (ON Duty: 50 %)
- Operating Temperature Tj: -40 °C to +150 °C

Package

VSON10FV3030

W (Typ) x D (Typ) x H (Max)

3.0 mm x 3.0 mm x 1.0 mm



Features

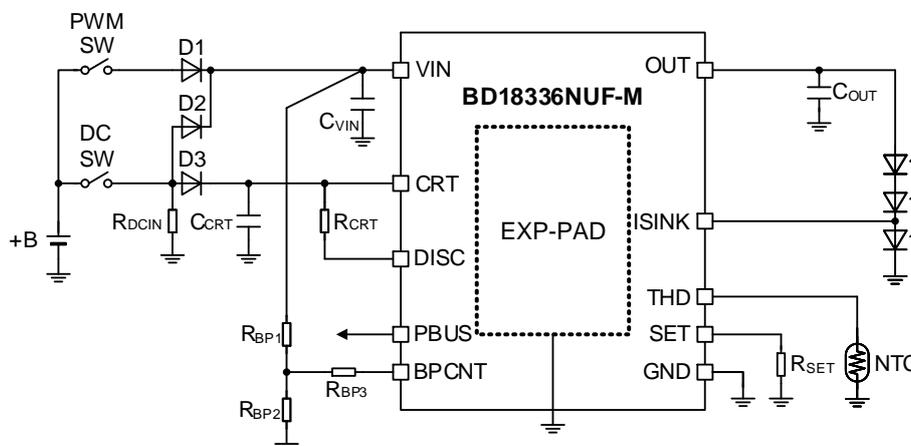
- AEC-Q100 Qualified^(Note 1)
- CR Timer for PWM Dimming
- Thermal De-rating Function (THD)
- LED Open Detection
- Output Short Circuit Protection (OUT SCP)
- SET Pin Short Circuit Protection (SET SCP)
- Over Voltage Mute Function (OVM)
- Current Bypass Function at Reduced-Voltage
- Disable LED Open Detection Function at Reduced-Voltage (OPM)
- Output for Fault Flag / Input for Output Current OFF Control Signal (PBUS)

(Note 1) Grade1

Applications

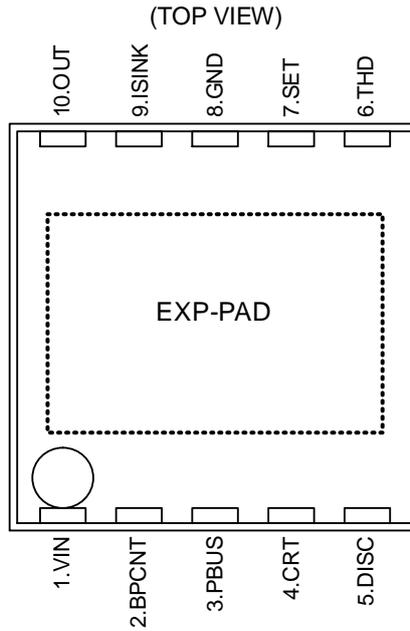
- Automotive LED Exterior Lamps
(Rear Lamp, Turn Lamp, DRL/Position Lamp, Fog Lamp)
- Automotive Interior Lamps
(Air Conditioner Lamp, Interior Light, Cluster Light etc.)

Typical Application Circuit



○Product structure: Silicon integrated circuit ○This product has no designed protection against radioactive rays.

Pin Configuration



Pin Descriptions

Pin No.	Pin Name	Function
1	VIN	Power supply input
2	BPCNT	Current bypass function at reduced-voltage setting ^(Note 1)
3	PBUS	Output for fault flag / Input for output current OFF control signal ^(Note 2)
4	CRT	CR timer setting 1 ^(Note 3)
5	DISC	CR timer setting 2 ^(Note 3)
6	THG	Thermal de-rating setting ^(Note 4)
7	SET	Output current setting ^(Note 1)
8	GND	GND
9	ISINK	Current sink pin for current bypass function at reduced-voltage
10	OUT	Current output
-	EXP-PAD	Heat radiation pad. The EXP-PAD is connected to GND.

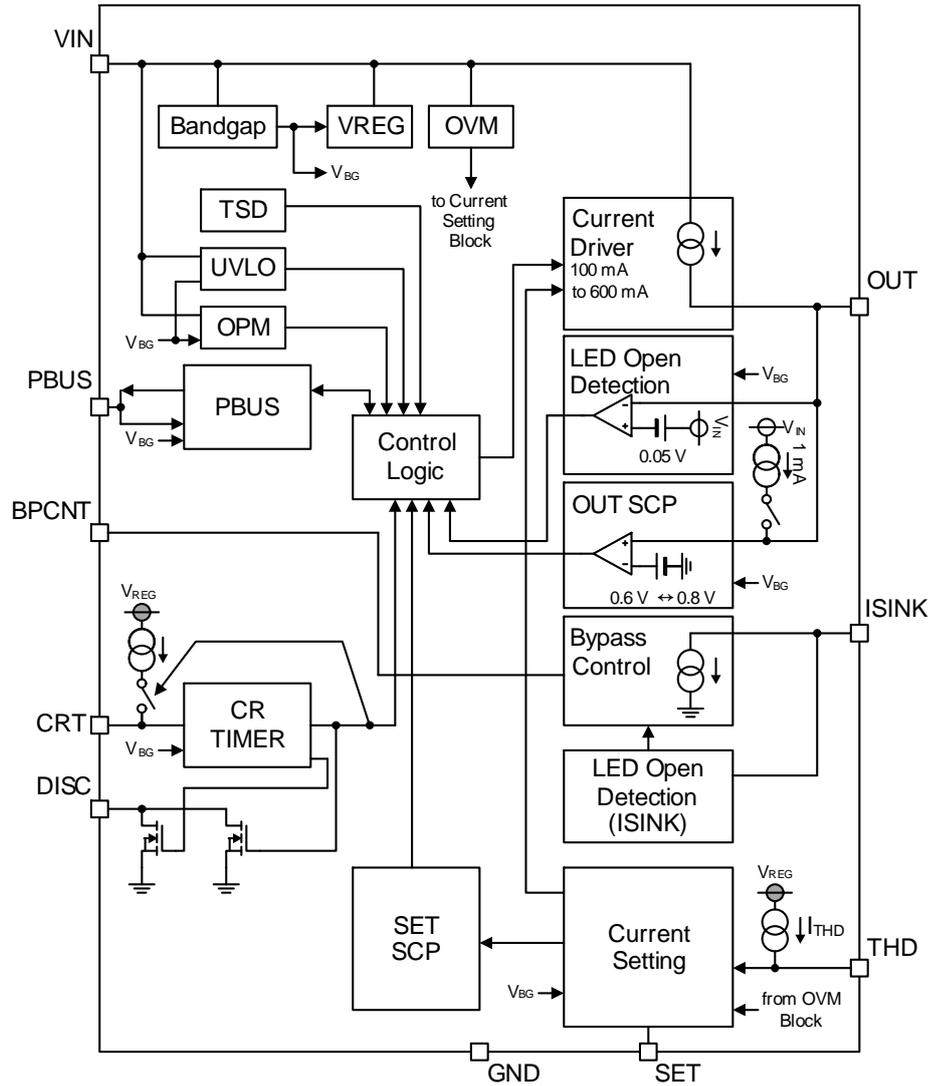
(Note 1) Do not connect external capacitor.

(Note 2) Open the PBUS pin when not in use output for fault flag / input for output current OFF control signal.

(Note 3) Short the CRT pin to the VIN pin and open the DISC pin when in use at DC mode only.

(Note 4) Open the THG pin when not in use thermal de-rating function.

Block Diagram



Description of Blocks(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)**1. Table of Operations**

The BD18336NUF-M has a built-in CR timer for PWM dimming and it is possible to change between PWM dimming mode and DC mode. Once the V_{IN} pin voltage V_{IN} is 17.4 V (Typ) or more, the output current I_{OUT} is limited to suppress the heat generation from the IC.

It is possible to detect the LED open state or short circuit state by monitoring the OUT pin voltage. In case of the LED abnormality detection, it can notify the abnormality to the outside by changing the PBUS pin voltage to low.

The output current is also turned OFF when the Low signal is input to the PBUS pin.

In addition, under voltage lock out (UVLO) and thermal shutdown circuit (TSD) are built-in, which further increase system reliability.

The correspondence table is given below. For details, refer to functional description of each block.

Operation Mode	CRT Pin	Detecting Condition		Output Current (I_{OUT})	PBUS Pin
		[Detect]	[Release]		
DC	$V_{CRT} \geq 2.0\text{ V (Typ)}$	-	-	100 mA to 400 mA	-
PWM Dimming	Refer to Description of Blocks 4	-	-	Refer to Description of Blocks 4	-
Thermal De-rating (THD)	-	$V_{THD} \leq 0.8\text{ V (Typ)}$	$V_{THD} > 0.8\text{ V (Typ)}$	Refer to Description of Blocks 9	-
Over Voltage Mute (OVM)	-	$V_{IN} \geq 17.4\text{ V (Typ)}$	$V_{IN} < 17.4\text{ V (Typ)}$	Refer to Description of Blocks 10	-
LED Open Detection (OUT Pin)	-	$V_{OUT} \geq V_{IN} - 0.050\text{ V (Typ)}$ and $V_{IN} \geq 11.0\text{ V (Typ)}$	$V_{OUT} < V_{IN} - 0.050\text{ V (Typ)}$ or $V_{IN} < 11.0\text{ V (Typ)}$	OFF	Low
LED Open Detection (ISINK Pin)	-	$V_{ISINK} \geq 4.1\text{ V (Typ)}$	$V_{ISINK} < 4.1\text{ V (Typ)}$	-	-
Output Short Circuit Protection (OUT SCP)	-	$V_{OUT} \leq 0.6\text{ V (Typ)}$	$V_{OUT} \geq 0.8\text{ V (Typ)}$	OFF	Low
SET Pin Short Circuit Protection (SET SCP)	-	$I_{SET} \leq 0.5\text{ mA (Typ)}$	$I_{SET} > 0.5\text{ mA (Typ)}$	OFF	Low
Input for Output Current OFF Control Signal (PBUS)	-	$V_{PBUS} \leq 0.6\text{ V (Typ)}$	$V_{PBUS} \geq 2.4\text{ V (Typ)}$	OFF	$V_{PBUS} \leq 0.6\text{ V (Typ)}$ input
Under Voltage Lock Out (UVLO)	-	$V_{IN} \leq 4.75\text{ V (Typ)}$	$V_{IN} \geq 5.25\text{ V (Typ)}$	OFF	High
Thermal Shutdown Circuit (TSD)	-	$T_j \geq 175\text{ }^\circ\text{C (Typ)}$	$T_j \leq 150\text{ }^\circ\text{C (Typ)}$	OFF	Low

Description of Blocks – continued

(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

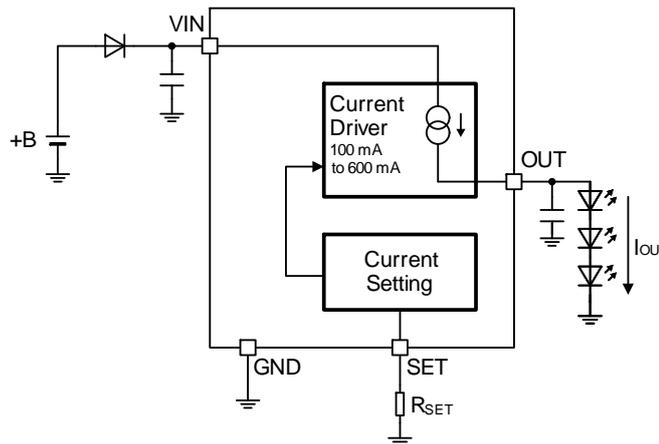
2. Output Current I_{OUT} Setting

The output current I_{OUT} can be set by the value of the output current setting resistor R_{SET} .

$$I_{OUT} = \frac{K_{SET}}{R_{SET}} \quad [\text{mA}]$$

where:

K_{SET} is the output current setting coefficient, 2400 (Typ).
 R_{SET} is the output current setting resistor. [k Ω]



Output Current Setting

2.1 Relationship between V_{IN} Pin Voltage V_{IN} and Output Current I_{OUT}

Set the V_{IN} pin voltage V_{IN} and output current I_{OUT} to satisfy the following relationship.

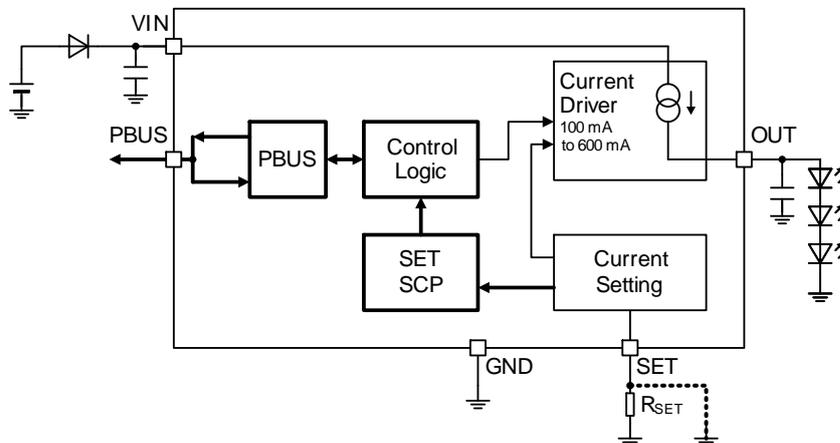
$$V_{IN} \geq V_{f_LED} \times N + V_{DR} \quad [\text{V}]$$

Where:

V_{IN} is the V_{IN} pin voltage.
 V_{f_LED} is the forward voltage of LED.
 N is the number of LED.
 V_{DR} is the drop voltage between the V_{IN} and the OUT pin.

3. SET Pin Short Circuit Protection (SET SCP)

Once the current which flows through the SET pin is more than or equal to the SET pin short circuit protection threshold current I_{SET_SH} (0.50 mA (Typ)), the output current I_{OUT} is turned off to prevent thermal damage of the IC, and it can notify the abnormality to the outside by changing the PBUS pin output to low.



SET Pin Short Circuit Protection

Description of Blocks – continued

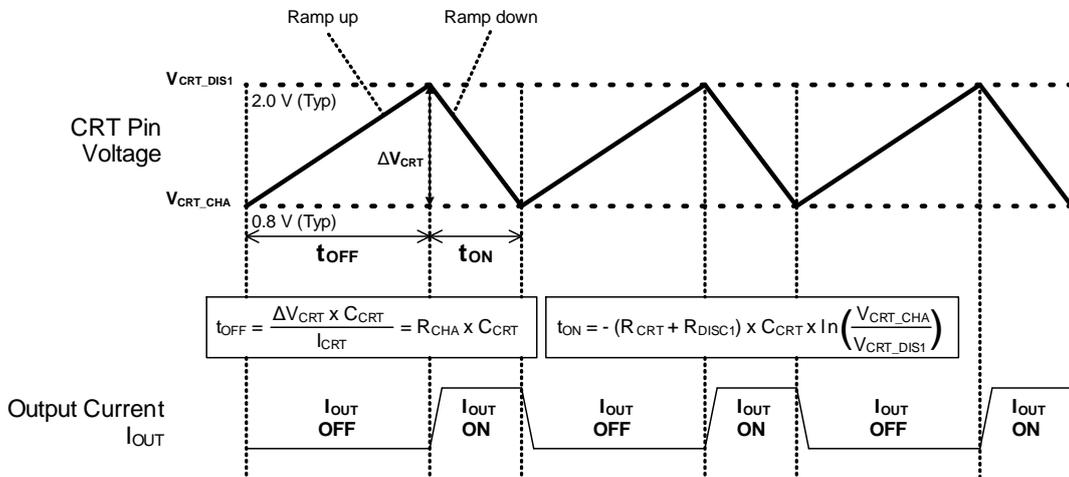
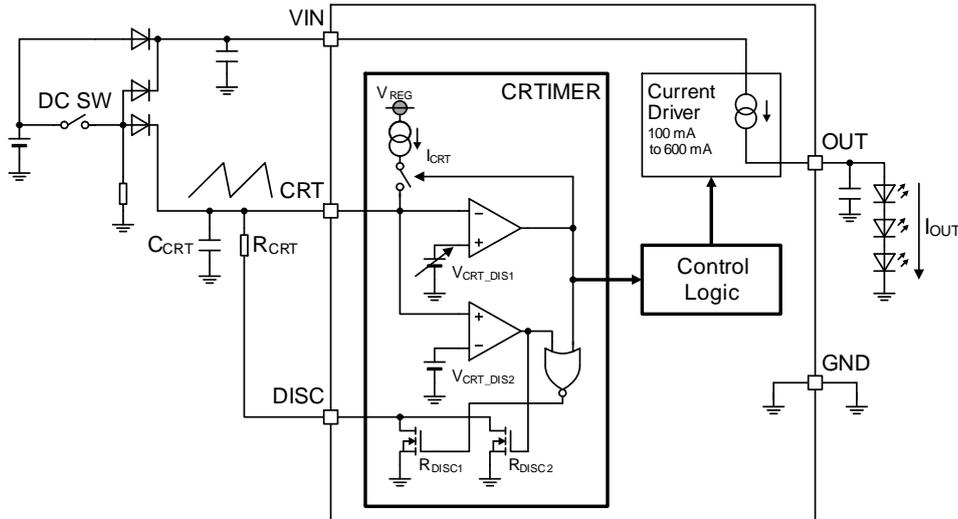
(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

4. PWM Dimming Operation

PWM dimming is performed by connecting external parts to the CRT pin and the DISC pin as shown below. PWM dimming frequency and ON duty width can be set by the values of the external resistor R_{CRT} and the external capacitor C_{CRT} . When use the DC mode only, connect the CRT pin to the VIN pin and open the DISC pin.

A triangular waveform is generated when the DC SW is open as shown below. Output current I_{OUT} is turned OFF while the CRT pin voltage ramps up and I_{OUT} is turned ON while the CRT pin voltage is ramp down.

Once the CRT pin voltage is $V_{C_{RT_DIS1}}$ (2.0 V (Typ)) or more, it turns to DC mode. And once the CRT pin voltage is more than $V_{C_{RT_DIS2}}$ (2.4 V (Typ)), the DISC pin ON resistance changes from R_{DISC1} (50 Ω (Typ)) to R_{DISC2} (5 k Ω (Typ)) and the power consumption of the IC is reduced by reducing the inflow current of the DISC pin.



PWM Dimming Operation

4. PWM Dimming Blocks – continued

4.1 CRT Pin Voltage Ramp Up Time t_{OFF} and Ramp Down Time t_{ON}

CRT pin voltage ramp up time t_{OFF} and ramp down time t_{ON} can be set by the following equations. Make sure that t_{ON} is set PWM minimum pulse width t_{MIN} to 50 μ s or more.

$$t_{OFF} = \frac{\Delta V_{CRT} \times C_{CRT}}{I_{CRT}} = R_{CHA} \times C_{CRT} \quad [\text{ms}]$$

$$t_{ON} = -(R_{CRT} + R_{DISC1}) \times C_{CRT} \times \ln \left(\frac{V_{CRT_CHA}}{V_{CRT_DIS1}} \right) \quad [\text{ms}]$$

where:

V_{CRT_CHA}	is the CRT pin charge voltage,	0.8 V (Typ).
V_{CRT_DIS1}	is the CRT pin discharge voltage 1,	2.0 V (Typ).
I_{CRT}	is the CRT pin charge current,	40 μ A (Typ).
C_{CRT}	is the capacitor for setting CR timer,	[μ F].
R_{CRT}	is the resistor for setting CR timer,	[k Ω].
R_{CHA}	is the CRT pin charge resistor,	30 k Ω (Typ).
R_{DISC1}	is the DISC pin ON resistor 1,	25 Ω (Typ).

4.2 PWM Dimming Frequency f_{PWM}

PWM frequency is defined by t_{ON} and t_{OFF} .

$$f_{PWM} = \frac{1}{t_{ON} + t_{OFF}} \quad [\text{Hz}]$$

4.3 ON Duty (D_{ON})

PWM ON duty is defined by t_{ON} and t_{OFF} .

$$D_{ON} = \frac{t_{ON}}{t_{ON} + t_{OFF}} \times 100 \quad [\%]$$

(Example) In case of $R_{CRT} = 3.6$ k Ω (Typ), $C_{CRT} = 0.1$ μ F (Typ)

$$t_{OFF} = R_{CHA} \times C_{CRT} = 30 \times 0.1 = 3.0 \quad [\text{ms}]$$

$$t_{ON} = -\left(R_{CRT} + \frac{R_{DISC1}}{1000}\right) \times C_{CRT} \times \ln \left(\frac{V_{CRT_CHA}}{V_{CRT_DIS1}} \right)$$

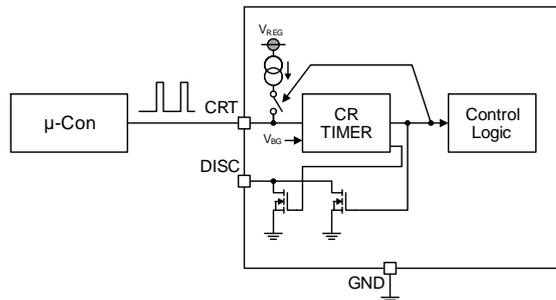
$$= -\left(3.6 + \frac{25}{1000}\right) \times 0.1 \times \ln \left(\frac{0.8}{2.0} \right) = 0.332 \quad [\text{ms}]$$

$$f_{PWM} = \frac{1}{t_{ON} + t_{OFF}} = \frac{1}{3.0 + 0.332} = 300 \quad [\text{Hz}]$$

$$D_{ON} = \frac{t_{ON}}{t_{ON} + t_{OFF}} \times 100 = \frac{0.332}{3.0 + 0.332} \times 100 = 10.0 \quad [\%]$$

4.4 PWM Dimming Operation Using External Signal

If input the external pulse signal to the CRT pin as shown below, make sure that input pulse signal high voltage ≥ 2.2 V and pulse signal low voltage ≤ 0.72 V. Also, open the DISC pin.



In Case External Pulse Signal Input to the CRT Pin

4. PWM Dimming Blocks – continued

4.5 About the Deviation of the CRT Pin Voltage Ramp Up/Down Time Due to Reverse Current Characteristics of Reverse Connection Protection Diodes

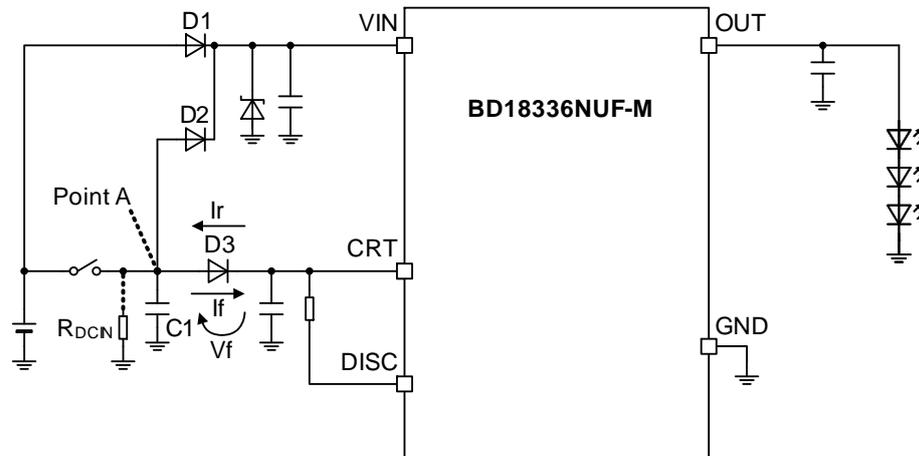
If this IC is used to drive LED as shown below, there is a possibility of the deviation of the CRT pin voltage ramp up/down time from the settings depends on reverse current characteristics of connected reverse current protection diodes (D2, D3).

Consider a diode which is recommended by ROHM or a diode which is 1 μA (Max) or less of reverse current characteristics because reverse current I_r of a diode especially increases at high temperature.

Since reverse current flows even with the recommended diodes, connect a resistor of R_{DCIN} of 10 $\text{k}\Omega$ or less between Point A and GND so that the voltage at point A does not rise.

●Mechanism of the deviation of the CRT pin voltage ramp up/down time from the settings.

- A) During the PWM dimming mode, Point A on the below figure is in the high impedance (Hi-Z) state.
- ↓
- B) Reverse current I_r of D2 and D3 flow to Point A.
(Power supply voltage is being input into the cathode of D2, so mainly reverse current of D2 flows to C1.)
→Reverse current I_r of D3 is added to the CRT pin charge current and discharge current, so the CRT pin voltage ramp up/down time deviates from the settings.
- ↓
- C) C1 gets charged, voltage at Point A rises.
- ↓
- D) Point A voltage is the CRT pin voltage of each IC or more.
- ↓
- E) Forward voltage V_f is generated to the diode D3.
- ↓
- F) D3 flows forward current I_f .
→Forward current I_f of D3 is added to the CRT pin charge current and discharge current, so the CRT pin voltage ramp up/down time deviates from the settings.
- ↓
- Repetition of B) to F).



Mechanism of the Deviation of the CRT Pin Voltage Ramp Up/Down Time due to Reverse Connection Protection Diodes

Description of Blocks – continued

(Unless otherwise specified, Tj = 25 °C, VIN = 13 V)

5. LED Open Detection

- In case any of Point A to Point C is in the open state
Once the OUT pin voltage VOUT becomes more than or equal to LED open detection voltage VOPD (VIN - 0.050 V (Typ)), it can notify the abnormality to the outside by changing the PBUS pin output to low.
- In case any of Point D or Point E is in the open state
Once the ISINK pin voltage becomes 4.1 V (Typ) or more, the ISINK pin current IISINK is turned OFF (Note 1). After that, once the OUT pin voltage VOUT becomes more than or equal to LED open detection voltage VOPD (VIN - 0.050 V (Typ)), it can notify the abnormality to the outside by changing the PBUS pin output to low.
(Note 1) While output current bypass function at reduced-voltage (Refer to Description of Function 13) is activated, the LED is lighted because the output current flows to the two upper side LEDs.

6. Disable LED Open Detection Function at Reduced-Voltage (OPM)

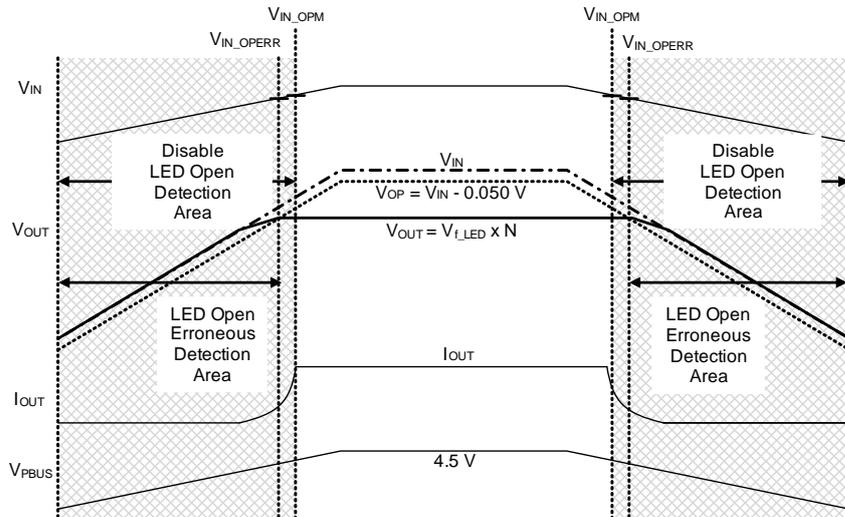
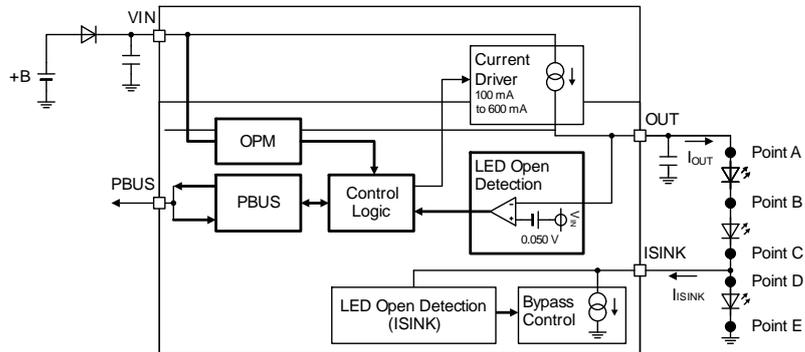
The disable LED open detection function serves to prevent LED open erroneous detection at the reduced-voltage during the ramp up/down of the VIN pin voltage. Even if the LED is in the open state, LED open is not detected until the VIN pin voltage becomes more than disable LED open detection voltage at reduced-voltage VIN_OPM (11.0 V (Typ)). Set VIN_OPM to satisfy the following formula.

$$V_{IN_OPM} > V_{IN_OPERR}$$

$$V_{IN_OPERR} = V_{f_LED_OPD} \times N + (V_{IN} - V_{OPD}) \quad [V]$$

where:

- VIN_OPM is the VIN pin disable LED open detection voltage at reduced-voltage.
- VIN_OPERR is the VIN pin LED open erroneous detection voltage at reduced-voltage.
- Vf_LED_OPD is the LED Vf at LED open release.
- N is the number of LED.
- VOPD is the LED open detection voltage.



VIN Pin Disable LED Open Detection Voltage at Reduced-Voltage and LED Open Erroneous Detection Voltage at Reduced-Voltage

Description of Blocks – continued

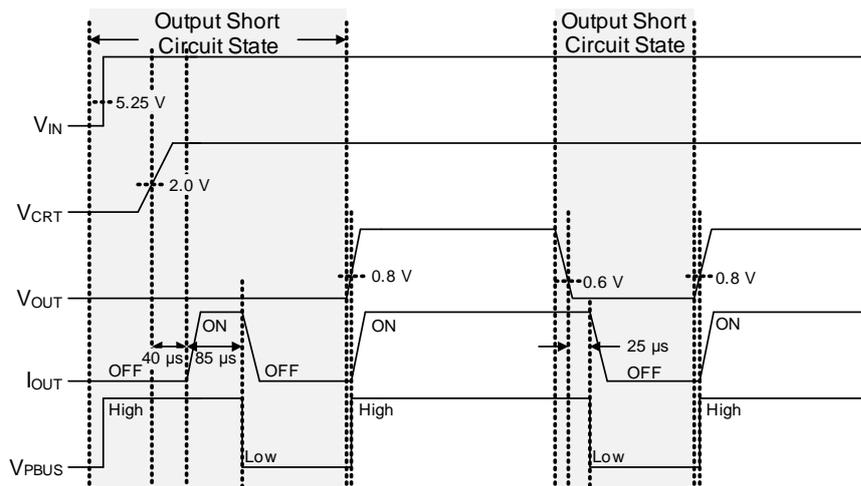
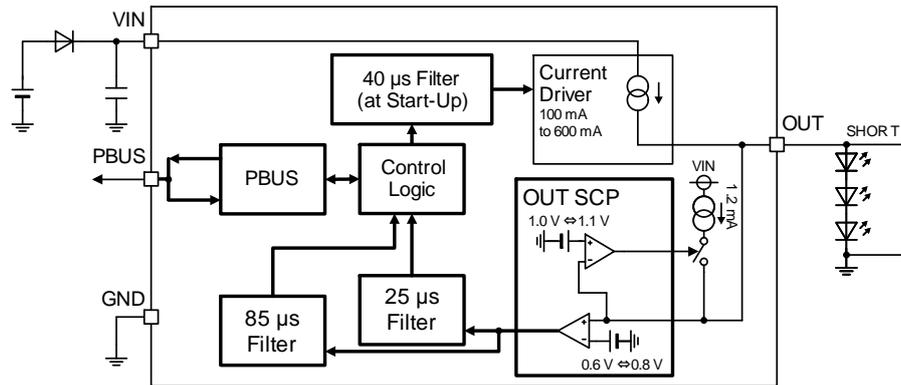
(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

7. Output Short Circuit Protection (OUT SCP)

Once the OUT pin voltage is less than or equal to the OUT pin short circuit protection voltage V_{SCP} (0.6 V (Typ)), then the short circuit protection is activated when SCP delay time t_{SCP1} (25 μs (Typ)) passes. At that time output current I_{OUT} is turned off to prevent the thermal damage of the IC and it can notify the abnormality to the outside by changing the PBUS pin output to low.

In order to avoid the malfunction when the power is turned on, the short circuit protection is not activated until the CRT pin voltage is more than 2.0 V (Typ) after UVLO is released.

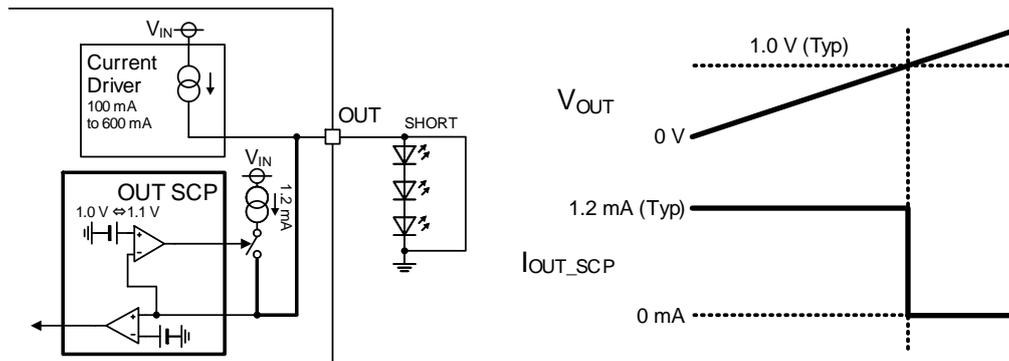
In addition, in case it is in the output short circuit state ($V_{OUT} < 0.6\text{ V}$ (Typ)) since the power is turned on, the output short circuit protection is activated when $V_{CRT} > 2.0\text{ V}$ (Typ) condition is reached and $t_{I_{OUT_ON}}$ (40 μs (Typ)) and t_{SCP2} (85 μs (Typ)) pass, after UVLO is released.



Output Short Circuit Protection (OUT SCP)

7.1 Current at OUT Pin Short Circuit

The OUT pin sources the OUT pin short circuit current I_{OUT_SCP} (1.2 mA (Typ)) once its voltage is less than 1.0 V (Typ) in order to prevent the malfunction of the short circuit protection.



Current at OUT Pin Short Circuit

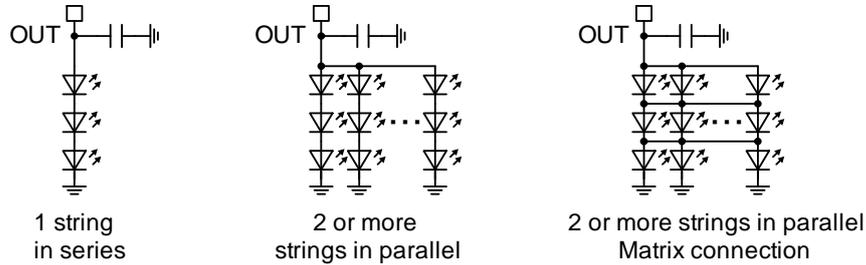
Description of Blocks – continued

(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

8. Caution of Using LED Open Detection and Output Short Circuit Protection

8.1 Connection Method of LEDs to the OUT Pin

Protection functions could be enabled or disabled based on how LEDs are connected to the OUT pin.



Connection Method of LEDs

Connection Method	Output Short Circuit Protection	LED Open Detection
1 string in series	Detectable	Detectable
2 or more strings in parallel	Detectable	Not detectable ^(Note 1)
2 or more strings in parallel (Matrix connection)	Detectable	Not detectable ^(Note 2)

^(Note 1) Detectable only when 1 or more LEDs are open in all strings.

^(Note 2) Detectable only when all LEDs from any string are open.

8.2 The Enable Zone of LED Open Detection and Output Short Circuit Protection, and Hi-Z Zone of the OUT Pin

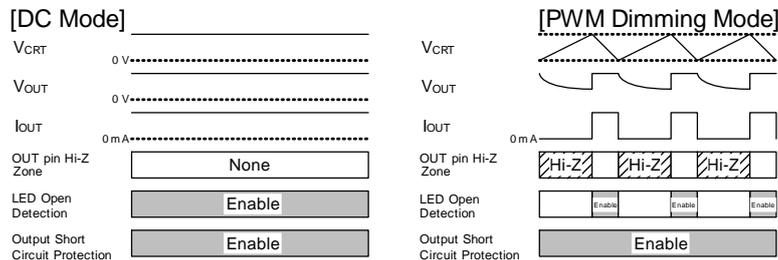
The enable zone of LED open detection and output short circuit protection is different between DC mode and PWM dimming mode.

- DC mode : LED open detection and output short circuit protection are enable in all zone.
- PWM dimming mode : LED open detection is enable in only CRT ramp down zone.
Output short circuit protection is enable in all zone.

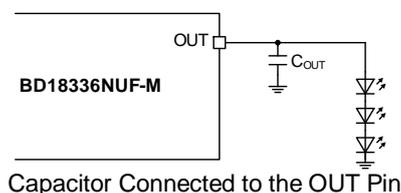
There is a zone which the OUT pin becomes Hi-Z at PWM dimming mode. During this time noise^(Note 3) may affect the decrease of the OUT pin voltage and cause malfunction of output short circuit protection. To prevent this, consider measurements such as connecting a capacitor C_{OUT} ^(Note 4) between the OUT pin and GND nearby IC. (Recommended value by ROHM: $C_{OUT} = 0.1\text{ }\mu\text{F}$ GCM188L81H104KA42 murata)

^(Note 3) Conducted noise, Radiated noise, Crosstalk of wiring and connector etc.

^(Note 4) In case connecting a capacitor with $0.1\text{ }\mu\text{F}$ or more, do evaluation of a delay time from the power-on of V_{IN} until output current I_{OUT} flows and pulse width of output current I_{OUT} at PWM dimming mode. (Refer to example of evaluation: [Description of Blocks 8.3](#))



The Enable Zone of LED Open Detection, Output Short Circuit Protection, and Hi-Z Zone of the OUT Pin

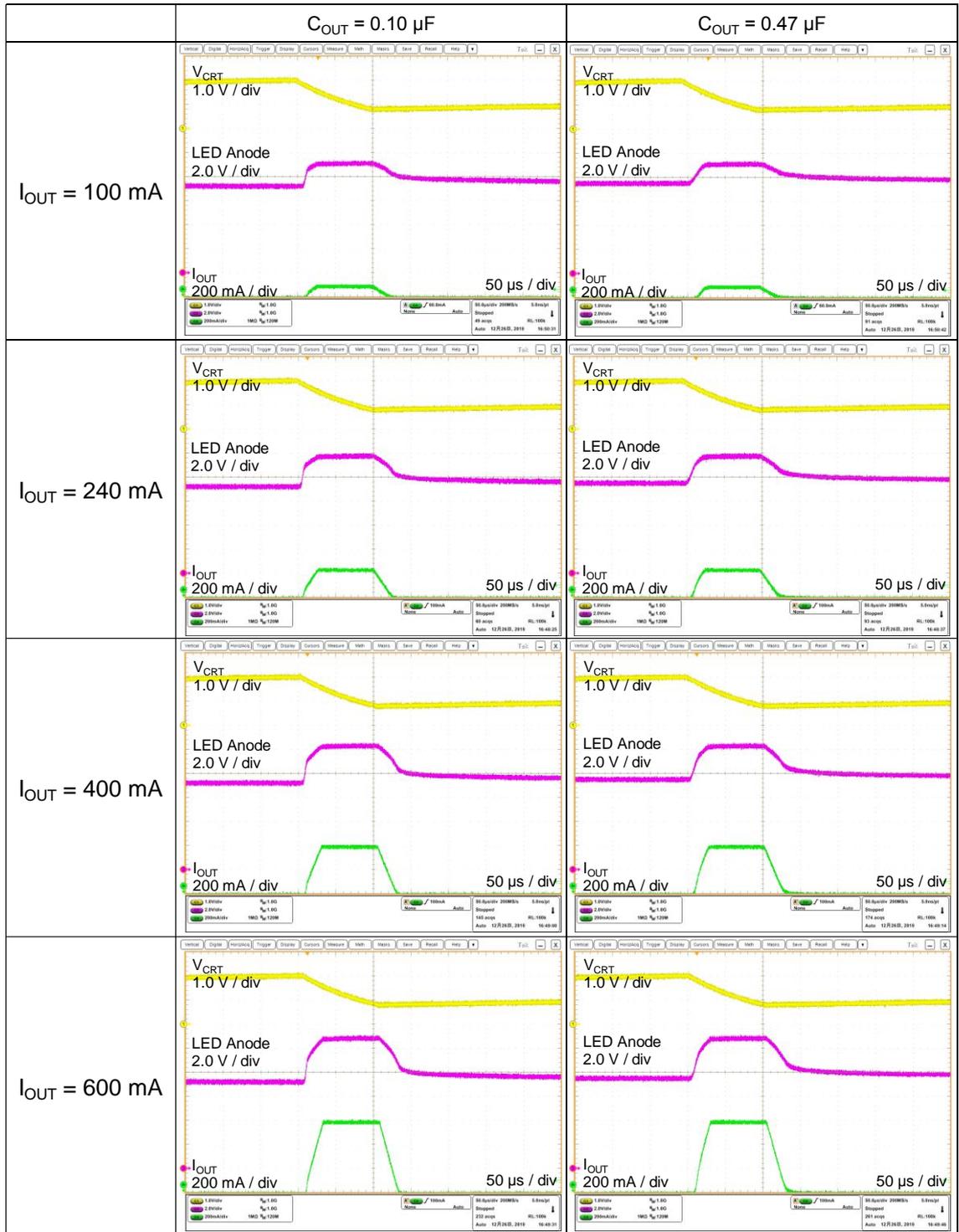


Capacitor Connected to the OUT Pin

8. Caution of Using LED Open Detection and Output Short Circuit Protection – continued

8.3 Evaluation Example of PWM Dimming I_{OUT} Pulse Width

Evaluation condition: $V_{IN} = 13\text{ V}$, $T_j = 25\text{ }^\circ\text{C}$, 3 White LEDs in series, PWM ON Duty = 3.2 %, Pulse width = 0.105 ms, PWM Frequency = 300 Hz

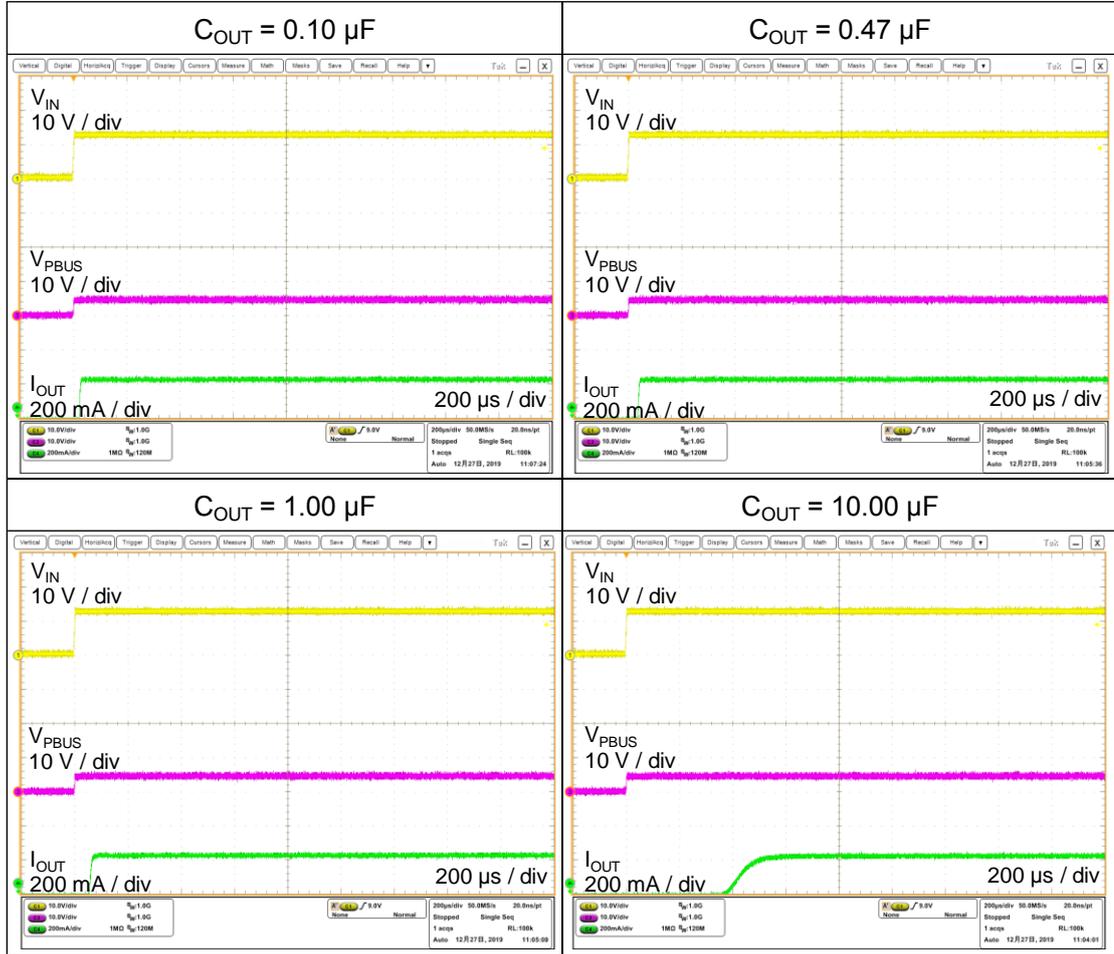


8. Caution of Using LED Open Detection and Output Short Circuit Protection – continued

8.4 Maximum Capacitance Value Connected to the OUT Pin (C_{OUT})

When the capacitance connected to the OUT pin is above the recommended range (1.0 μF or more), the delay time of output rise time could be in around hundreds of microseconds. Below are examples of evaluation data for reference.

Measurement conditions: $V_{IN} = 13\text{ V}$, $T_j = 25\text{ }^\circ\text{C}$, DC mode, 3 LEDs in series



Capacitor Connected to the OUT Pin

Description of Blocks – continued

(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

9. Thermal De-rating Function (THD)

It is possible to reduce the output current I_{OUT} at high temperature and suppress the degradation of the LED by connecting a thermistor to the THD pin. Once the THD pin voltage is less than or equal to thermal de-rating start voltage V_{THDS} (0.8 V (Typ)), the output current I_{OUT} is reduced according to the THD pin voltage.

Open the THD pin when not using thermal de-rating function.

In case variation of the THD pin voltage is steep, take measures such as connecting a capacitor to the THD pin to prevent the output current chattering. In addition, evaluate I_{OUT} waveform on actual board because the output amplifier may not follow the steep variation.

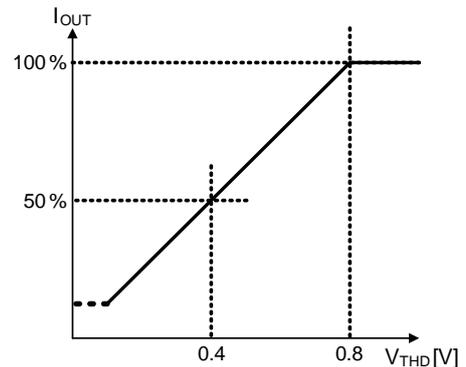
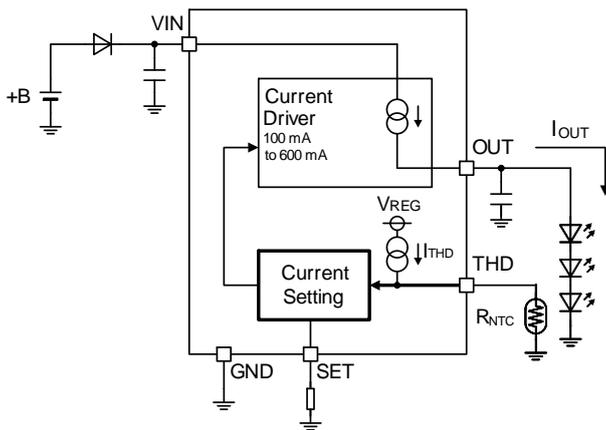
The thermal de-rating function can be set by the following formula.

$$V_{THD} = I_{THD} \times R_{NTC} \quad [V]$$

$$I_{OUT} (V_{THD} \leq 0.8\text{ V}) = \frac{K_{SET}}{R_{SET}} \times \frac{V_{THD}}{V_{SET}}$$

Where:

- I_{THD} is the THD pin source current, 200 μA (Typ).
- R_{NTC} is the resistance of NTC thermistor.
- I_{OUT} is the output current.
- V_{THD} is the THD pin voltage.
- V_{SET} is the SET pin voltage, 0.8 V (Typ).



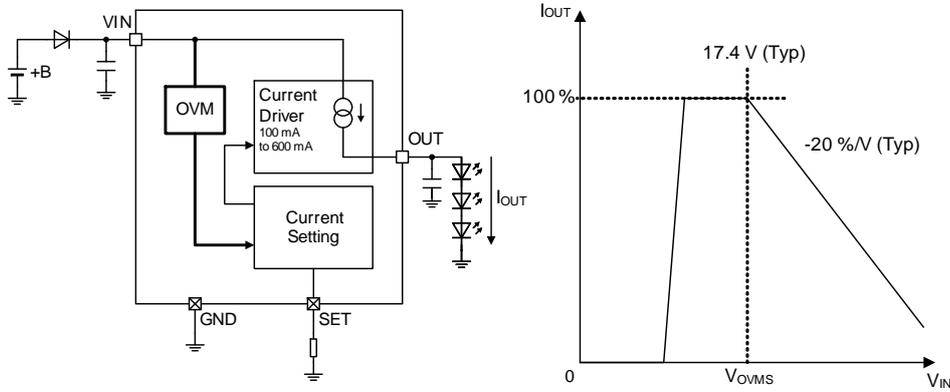
Thermal De-rating Function

Description of Blocks – continued

(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

10. Over Voltage Mute Function (OVM)

Once the V_{IN} pin voltage V_{IN} is over voltage mute start voltage V_{OVMS} 17.4 V (Typ) or more, the over voltage mute function is activated to decrease the output current I_{OUT} in order to suppress the heat generation from the IC. The output current I_{OUT} will decay at -20 %/V (Typ).



Over Voltage Mute Function (OVM)

11. Under Voltage Lock Out (UVLO)

UVLO is a protection circuit to prevent malfunction of the IC when the power is turned on or when the power is suddenly shut off. When the V_{IN} pin voltage V_{IN} is 4.75 V (Typ) or less, the output current I_{OUT} is turned OFF, and when the V_{IN} pin voltage V_{IN} increases to 5.25 V (Typ) or more, normal operation starts.

Description of Blocks – continued

(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

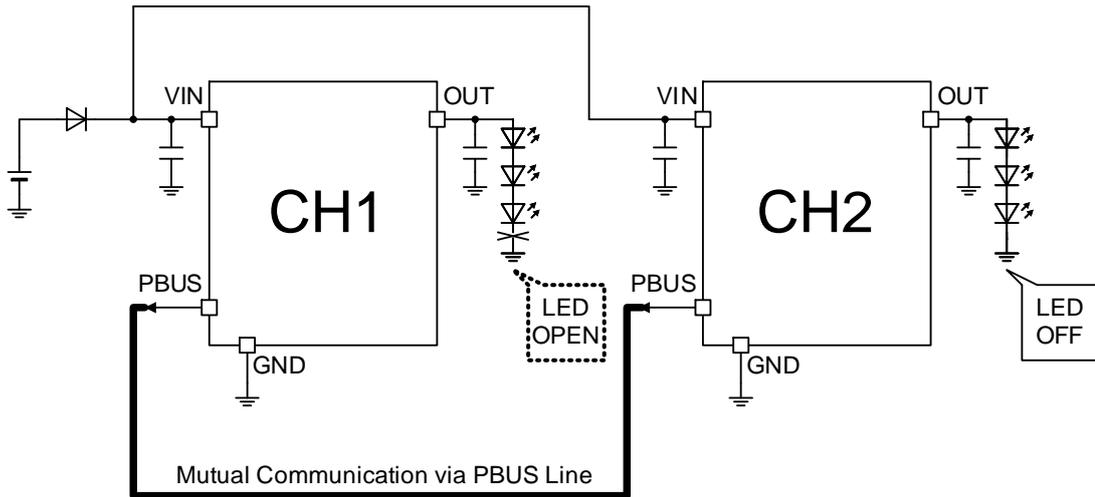
12. Output for Fault Flag / Input for Output Current OFF Control Signal (PBUS)

When abnormality such as LED open or output short circuit occurs, it can notify the abnormality to the outside by changing the PBUS pin output from high to low. In addition, by externally controlling the PBUS pin from high to low, the output current I_{OUT} is turned off. When using multiple ICs to drive multiple LED strings, it is possible to turn off all LED strings at once by connecting the PBUS pins of each CH as shown in the figure below, even if LED open or output short circuit occurs.

Caution of Using the PBUS Pin

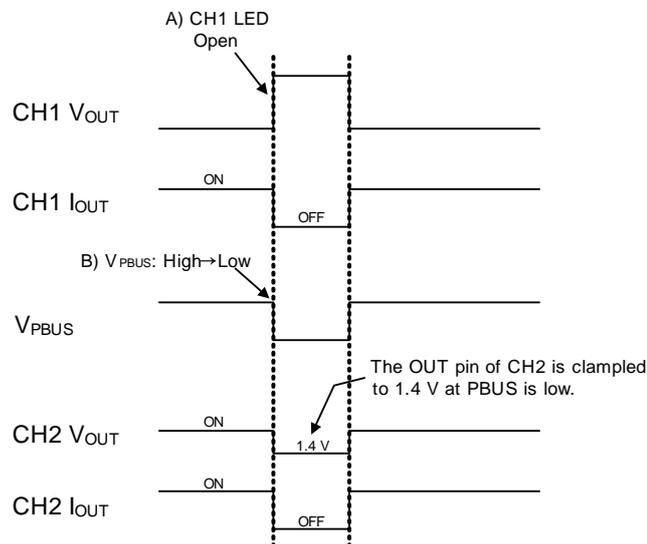
Do not connect to the PBUS pins other than below list items due to the difference of ratings, internal threshold voltages, and so on.

(BD18340FV-M, BD18341FV-M, BD18342FV-M, BD18343FV-M, BD18345EFV-M, BD18337EFV-M, BD18347EFV-M)



PBUS Function

12.1 Example of Protective Operation Due to LED Open



Example of Protective Operation

When CH1 is the LED open state, the PBUS pin of CH1 is changed from High to Low output. As the PBUS pin becomes Low, LED driver of CH2 turns OFF its output current. The OUT pin voltage is clamped to 1.4 V (Typ) during the OFF period, in order to prevent malfunction of output short circuit.

Description of Blocks – continued

(Unless otherwise specified, Tj = 25 °C, VIN = 13 V)

13. Current Bypass Function at Reduced-Voltage

The BD18336NUF-M is built-in current bypass function at reduced-voltage.

When the VIN_DIV which is the resistor divider of the VIN pin voltage VIN is more than the BPCNT reference voltage VBP (2.0 V (Typ)), the ISINK pin sink current ISINK decreases. The output current IOUT changes linearly.

The ISINK pin sink current ISINK can be set by the following formula.

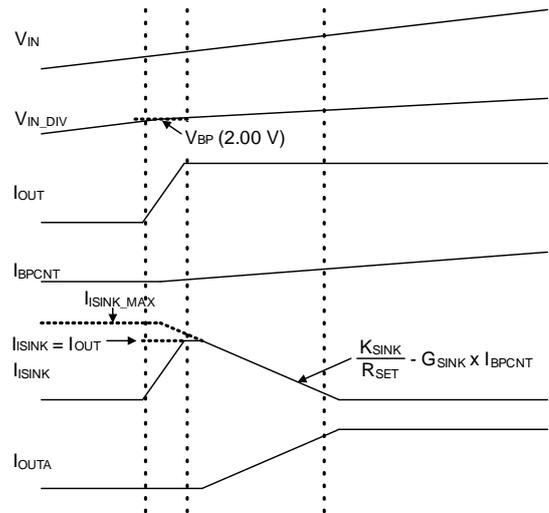
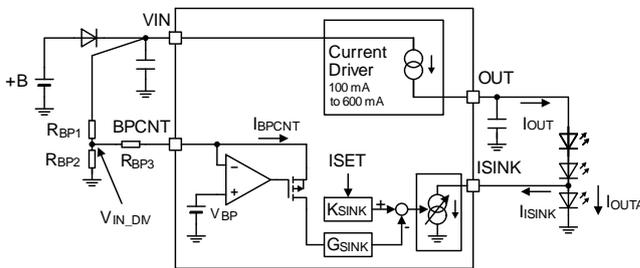
$$I_{ISINK} = \frac{K_{SINK}}{R_{SET}} - G_{SINK} \times I_{BPCNT} \div 10^3 \quad [mA]$$

$$I_{BPCNT} = \frac{1}{R_{BP3}} \left\{ \frac{R_{BP2} \times (R_{BP1} \times V_{BP} + R_{BP3} \times V_{IN})}{R_{BP1} \times R_{BP2} + R_{BP3} \times (R_{BP1} + R_{BP2})} - V_{BP} \right\} \times 10^3 \geq 0 \quad [\mu A]$$

$$I_{ISINK_MAX} = \frac{K_{SINK}}{R_{SET}} \quad [mA]$$

Where:

- K_{SINK} is the ISINK current setting coefficient, 3000 (Typ).
- R_{SET} is the output current setting resistor, [kΩ]
- G_{SINK} is the ISINK current gain, -7300 (Typ).
- I_{BPCNT} is the BPCNT pin input current, [μA]
- R_{BP1} is the resistor for setting current bypass 1, [kΩ]
- R_{BP2} is the resistor for setting current bypass 2, [kΩ]
- R_{BP3} is the resistor for setting current bypass 3, [kΩ]
- V_{BP} is the BPCNT reference voltage, 2.00 V (Typ)
- I_{ISINK_MAX} is the ISINK pin maximum sink current, [mA]



Current Bypass Function at Reduced-Voltage

When not using the current bypass function at reduced-voltage, the ISINK pin is connected to the GND and the BPCNT pin is connected with pull-down resistor or to the GND. In case the BPCNT pin is connected to the GND, over current may flow when the BPCNT pin is shorted to the VIN pin. Do enough evaluation including external parts.

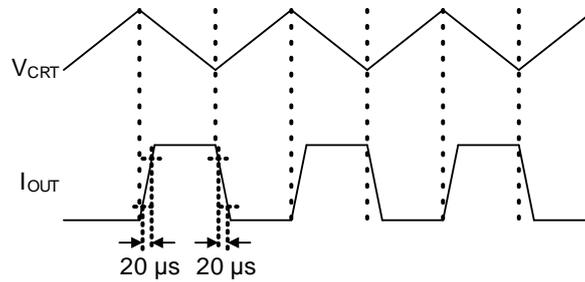
Description of Blocks – continued

(Unless otherwise specified, $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

14. Output Current Rise/Fall Time Fixed Function

The BD18336NUF-M has built-in output current rise/fall time fixed function.

It can suppress the noise generated to the power supply line by fixing the output current rise/fall time to $20\text{ }\mu\text{s}$ (Typ).



Output Current Rise/Fall Time Fixed Function

Absolute Maximum Ratings (Ta = 25 °C)

No.	Parameter	Symbol	Rating	Unit
A-1	VIN Pin Voltage	V _{IN}	-0.3 to +42.0	V
A-2	CRT, DISC Pin Voltage	V _{CRT} , V _{DISC}	-0.3 to +42.0	V
A-3	OUT Pin Voltage	V _{OUT}	-0.3 to V _{IN} +0.3 < +42.0	V
A-4	PBUS, BPCNT, ISINK Pin Voltage	V _{PBUS} , V _{BPCNT} , V _{ISINK}	-0.3 to +20.0	V
A-5	SET, THD Pin Voltage	V _{SET} , V _{THD}	-0.3 to +7.0	V
A-6	Storage Temperature Range	T _{stg}	-55 to +150	°C
A-7	Maximum Junction Temperature	T _{jmax}	150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance (Note 1)

Parameter	Symbol	Thermal Resistance (Typ)		Unit
		1s ^(Note 3)	2s2p ^(Note 4)	
VSON10FV3030				
Junction to Ambient	θ_{JA}	158.00	46.00	°C/W
Junction to Top Characterization Parameter ^(Note 2)	Ψ_{JT}	23.00	12.00	°C/W

(Note 1) Based on JESD51-2A (Still-Air).

(Note 2) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 3) Using a PCB board based on JESD51-3.

(Note 4) Using a PCB board based on JESD51-5, 7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt

Top	
Copper Pattern	Thickness
Footprints and Traces	70 μ m

Layer Number of Measurement Board	Material	Board Size	Thermal Via ^(Note 5)	
			Pitch	Diameter
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt	1.20 mm	Φ 0.30 mm

Top		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70 μ m	74.2 mm x 74.2 mm	35 μ m	74.2 mm x 74.2 mm	70 μ m

(Note 5) This thermal via connects with the copper pattern of all layers.

Recommended Operating Conditions

No.	Parameter	Symbol	Min	Typ	Max	Unit
O-1	Supply Voltage ^(Note 1)	V_{IN}	5.5	13.0	20.0	V
O-2	OUT Pin Maximum Output Current (DC)	$I_{OUT(DC)}$	-	-	400	mA
O-3	OUT Pin Maximum Output Current (ON Duty: 50 %)	$I_{OUT(50\%DUTY)}$	-	-	600	mA
O-4	PWM Dimming Frequency	f_{PWM}	200	-	750	Hz
O-5	PWM Minimum Pulse Width ^(Note 2)	t_{MIN}	50	-	-	μs
O-6	Operating Temperature	T_{opr}	-40	-	+150	$^{\circ}C$

(Note 1) ASO should not be exceeded.

(Note 2) It is the same as when the pulse input to the CRT pin.

External Parts Setting Range

No.	Parameter	Symbol	Min	Typ	Max	Unit
P-1	Capacitor Connecting The VIN Pin at Operating DC Mode Only ^(Note 3)	C_{VIN_DC}	0.47	-	-	μF
P-2	Capacitor Connecting The VIN Pin at Operating PWM Mode ^(Note 3)	C_{VIN_PWM}	1.0	-	-	μF
P-3	Capacitor Connecting The OUT Pin ^(Note 4) (No need at $I_{LED} < 400$ mA) (Need at $I_{LED} \geq 400$ mA)	C_{OUT}	0.1	-	1.0	μF
P-4	Capacitor for Setting CR Timer	C_{CRT}	0.047	0.100	0.220	μF
P-5	Resistor for Setting CR Timer	R_{CRT}	0.1	-	50.0	k Ω
P-6	Resistor for Setting Output Current	R_{SET}	4.0	-	24.0	k Ω
P-7	Resistor for DCIN Pull-down	R_{DCIN}	-	-	10	k Ω
P-8	Resistor for Setting BPCNT 1	R_{BP1}	10.5	-	46.7	k Ω
P-9	Resistor for Setting BPCNT 2	R_{BP2}	3.3	-	30.0	k Ω
P-10	Resistor for Setting BPCNT 3	R_{BP3}	0.24	-	96.50	k Ω

(Note 3) Connect C_{VIN_DC} or C_{VIN_PWM} within 10 mm from the IC. If they are connected more than 10 mm from the IC, there is a possibility of unstable operation such as oscillation of output current I_{OUT} etc. So consider with enough evaluation on actual board

(Note 4) If a long wire connects from the OUT pin to the LED anode, there is a possibility of output current I_{OUT} oscillation.

After consideration with enough evaluation, connect a capacitor connecting to the OUT pin C_{OUT} between the OUT pin and GND to prevent oscillation.

Electrical Characteristics

(Unless otherwise specified T_j = -40 °C to +150 °C, V_{IN} = 13 V)

No.	Parameter	Symbol	Limit			Unit	Conditions	
			Min	Typ	Max			
Circuit Current								
E-1	VIN Pin Circuit Current at Normal Mode	I _{VIN1}	-	2.6	5.0	mA	R _{SET} = 24 kΩ	
E-2	VIN Pin Circuit Current at LED Open Detection	I _{VIN2}	-	2.4	5.0	mA	V _{OUT} = Open R _{SET} = 24 kΩ	
E-3	VIN Pin Circuit Current at PBUS = Low	I _{VIN3}	-	2.7	5.0	mA	V _{PBUS} = 0 V R _{SET} = 24 kΩ	
Output Current								
E-4	OUT OFF Current	I _{OUT_OFF}	-	-	1.0	μA	V _{OUT} = 2.0 V V _{CR1} = 0 V, T _j = 25 °C	
E-5	Drop Voltage Between VIN Pin and OUT Pin 1	V _{DR1}	-	-	0.77	V	T _j = -40 °C I _{OUT} = 600 mA	
E-6	Drop Voltage Between VIN Pin and OUT Pin 2	V _{DR2}	-	-	0.88	V	T _j = +25 °C I _{OUT} = 600 mA	
E-7	Drop Voltage Between VIN Pin and OUT Pin 3	V _{DR3}	-	-	1.10	V	T _j = +150 °C I _{OUT} = 600 mA	
E-8	Output Current Rise Time	I _{OUT_RISE}	10	20	30	μs	I _{OUT} = 20 % → 80 % R _{SET} = 10 kΩ	
E-9	Output Current Fall Time	I _{OUT_FALL}	10	20	30	μs	I _{OUT} = 80 % → 20 % R _{SET} = 10 kΩ	
E-10	The Difference Between Output Current Rise Time and Fall Time	ΔI _{RISEFALL}	-5	0	5	μs	R _{SET} = 10 kΩ	
LED Open Detection								
E-11	OUT Pin LED Open Detection Voltage	V _{OPD}	V _{IN} - 0.080	V _{IN} - 0.050	V _{IN} - 0.020	V		
E-12	ISINK Pin LED Open Detection Voltage	V _{OPISINK}	3.8	4.1	4.5	V		
Output Short Circuit Protection (OUT SCP)								
E-13	Current at OUT Pin Short Circuit	I _{OUT_SCP}	0.2	1.2	2.0	mA		
E-14	OUT Pin Short Circuit Protection Voltage	V _{SCP}	0.5	0.6	0.7	V		
E-15	OUT Pin Short Circuit Protection Release Voltage	V _{SCPR}	0.7	0.8	0.9	V		
E-16	Current ON Voltage at OUT Pin Short Circuit	V _{ISCPON}	0.9	1.0	1.2	V		
E-17	SCP Delay Time	t _{SCP1}	10	25	50	μs		
E-18	SCP Disable Time at Power On	t _{SCP2}	-	85	-	μs		
Output Current Setting 1								
E-19	Output Current Setting Coefficient	K _{SET}	2280	2400	2520	-	R _{SET} = 4 kΩ to 10 kΩ	T _j = -40 °C to +150 °C
			2270	2350	2430		R _{SET} = 10 kΩ to 16 kΩ	T _j = 25 °C
			2250	2420	2590		R _{SET} = 10 kΩ to 16 kΩ	T _j = 150 °C
			2160	2400	2640		R _{SET} = 10 kΩ to 16 kΩ	T _j = -40 °C to +150 °C
			2160	2400	2640		R _{SET} = 16 kΩ to 24 kΩ	T _j = -40 °C to +150 °C

Electrical Characteristics – continued(Unless otherwise specified T_j = -40 °C to +150 °C, V_{IN} = 13 V)

No.	Parameter	Symbol	Limit			Unit	Conditions
			Min	Typ	Max		
Output Current Setting 2							
E-20	Reference Voltage for Output Current Setting	V _{SET_REF}	0.72	0.80	0.88	V	V _{SET}
E-21	SET Pin Short Circuit Protection Threshold Current	I _{SET_SH}	0.24	0.50	1.20	mA	
E-22	Output Current On Delay Time at Power On	t _{IOUT_ON}	-	40	100	μs	V _{IN} = 0 V → 13 V t _{IOUT_ON} = t _{IOUT} (80%) – t _{IOUT} (@ V _{IN} = V _{UVLOR}) R _{SET} = 24 kΩ
Thermal De-Rating (THD)							
E-23	THD Pin Source Current	I _{THD}	190	200	210	μA	
E-24	Thermal De-Rating Start Voltage	V _{THDS}	0.76	0.80	0.84	V	V _{THD}
E-25	Thermal De-Rating Gain	G _{THD}	-131.3	-125.0	-118.7	%/V	$\frac{\Delta I_{OUT}}{\Delta V_{THD}}$ V _{THD} : 0.667 V → 0.333 V V _{IN} = 13 V
CR Timer for PWM Dimming							
E-26	CRT Pin Charge Current	I _{CRT}	36	40	44	μA	
E-27	CRT Pin Charge Voltage	V _{CRT_CHA}	0.72	0.80	0.88	V	
E-28	CRT Pin Discharge Voltage 1	V _{CRT_DIS1}	1.80	2.00	2.20	V	
E-29	CRT Pin Discharge Voltage 2	V _{CRT_DIS2}	2.10	2.40	3.00	V	V _{CRT} > V _{CRT_DIS2} R _{D1} → R _{D2}
E-30	CRT Pin Charge Resistance	R _{CHA}	28.5	30.0	31.5	kΩ	
E-31	CRT Discharge Constant	$\frac{V_{CRT_CHA}}{V_{CRT_DIS1}}$	0.38	0.40	0.42	V/V	
E-32	DISC Pin ON Resistance 1	R _{DISC1}	10	25	80	Ω	I _{DISC} = 10 mA
E-33	DISC Pin ON Resistance 2	R _{DISC2}	2.5	5	10	kΩ	I _{DISC} = 100 μA
E-34	CRT Pin Leakage Current	I _{CRT_LEAK}	-	-	10	μA	V _{CRT} = V _{IN}
Over Voltage Mute Function (OVM)							
E-35	Over Voltage Mute Start Voltage	V _{OVMs}	16.0	17.4	18.8	V	$\Delta I_{OUT} = -3\%$ $\Delta I_{OUT} =$ $\frac{I_{OUT} (@ V_{IN} = V_{OVM})}{I_{OUT} (@ V_{IN} = 13 V)} - 1$
E-36	Over Voltage Mute Gain	G _{OVM}	-	-20	-	%/V	$\frac{\Delta I_{OUT}}{\Delta V_{IN}}$ V _{THD} > 1.5 V
Function to Disable LED Open Detection at Reduced-Voltage (OPM)							
E-37	Release Voltage for Function to Disable LED Open Detection	V _{IN_OPM}	10.5	11.0	11.5	V	V _{IN}

Electrical Characteristics – continued

(Unless otherwise specified T_j = -40 °C to +150 °C, V_{IN} = 13 V)

No.	Parameter	Symbol	Limit			Unit	Conditions
			Min	Typ	Max		
Output for Fault Flag / Input for Output Current OFF Control Signal (PBUS)							
E-38	Input High Voltage	V _{PBUSH}	2.4	-	-	V	
E-39	Input Low Voltage	V _{PBUSL}	-	-	0.6	V	
E-40	PBUS Pin Source Current	I _{PBUS}	75	150	300	μA	V _{PBUS} = 0 V
E-41	PBUS Pin Output Low Voltage	V _{PBUS_OL}	-	-	0.6	V	I _{PBUS_EXT} = 3 mA
E-42	PBUS Pin Output High Voltage	V _{PBUS_OH}	3.5	4.5	5.5	V	I _{PBUS_EXT} = -10 μA
E-43	PBUS Pin Leakage Current	I _{PBUS_LEAK}	-	-	10	μA	V _{PBUS} = 5 V
Under Voltage Lock Out (UVLO)							
E-44	UVLO VIN Detection Voltage	V _{UVLOD}	4.50	4.75	5.00	V	V _{IN} : Sweep down
E-45	UVLO VIN Release Voltage	V _{UVLOR}	5.00	5.25	5.50	V	V _{IN} : Sweep up
E-46	UVLO VIN Hysteresis Voltage	V _{HYS}	-	0.5	-	V	
Current Bypass Function at Reduced-Voltage							
E-47	BPCNT Reference Voltage	V _{BP}	1.94	2.00	2.06	V	I _{BPCNT} = 10 μA
E-48	ISINK Current Setting Coefficient	K _{SINK}	2790	3000	3210	V	I _{BPCNT} = 0 μA K _{SINK} = I _{SINK} × R _{SET} R _{SET} = 24 kΩ
E-49	ISINK Current Gain	G _{SINK}	-7519	-7300	-7081	-	G _{SINK} = {I _{SINK1} (@I _{BPCNT} = 5 μA) - I _{SINK2} (@I _{BPCNT} = 10 μA)} / 5 μA R _{SET} = 24 kΩ
E-50	Voltage Between ISINK Pin and GND 1	V _{DRIS1}	-	-	0.88	V	T _j = -40 °C I _{SINK} = 600 mA
E-51	Voltage Between ISINK Pin and GND 2	V _{DRIS2}	-	-	1.00	V	T _j = +25 °C I _{SINK} = 600 mA
E-52	Voltage Between ISINK Pin and GND 3	V _{DRIS3}	-	-	1.25	V	T _j = +150 °C I _{SINK} = 600 mA

Typical Performance Curves (Reference Data)

(Unless otherwise specified $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

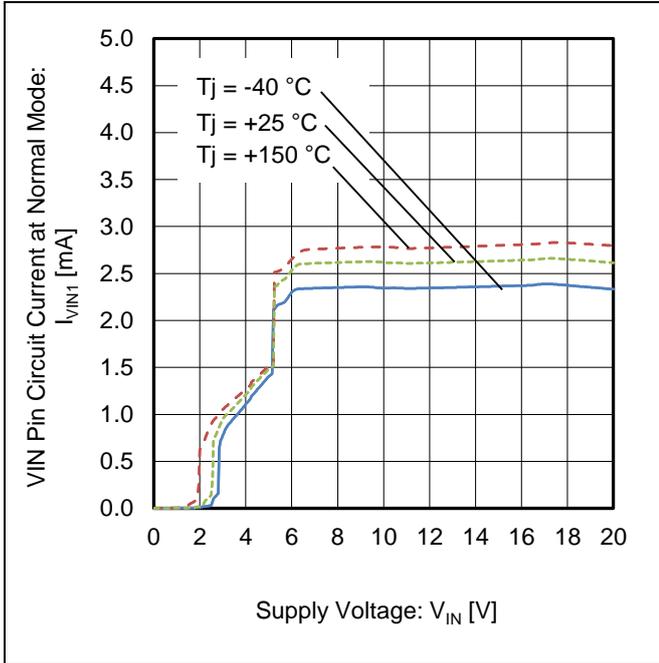


Figure 1. VIN Pin Circuit Current at Normal Mode vs Supply Voltage

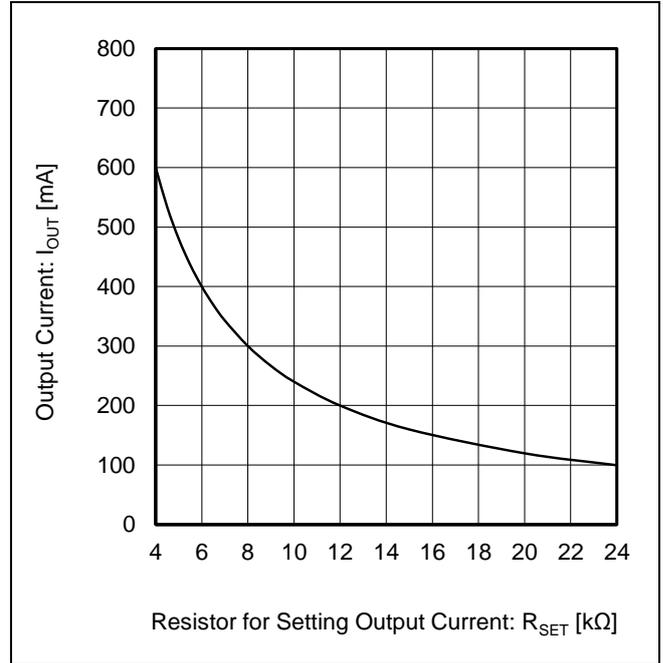


Figure 2. Output Current vs Resistor for Setting Output Current

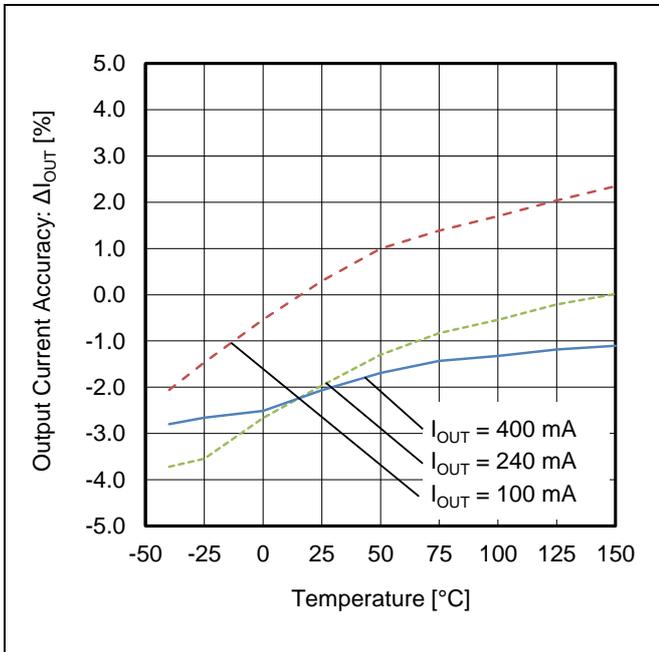


Figure 3. Output Current Accuracy vs Temperature

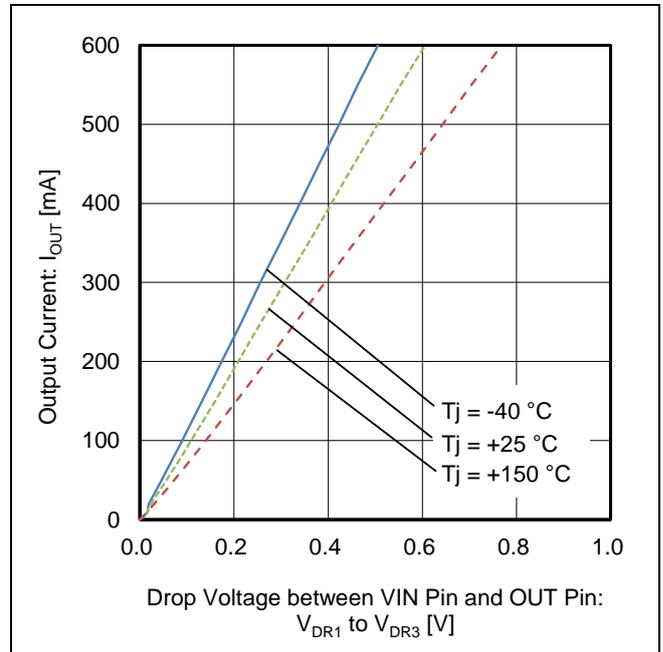


Figure 4. Output Current vs Drop Voltage between VIN Pin and OUT Pin

Typical Performance Curves (Reference Data) – continued

(Unless otherwise specified $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

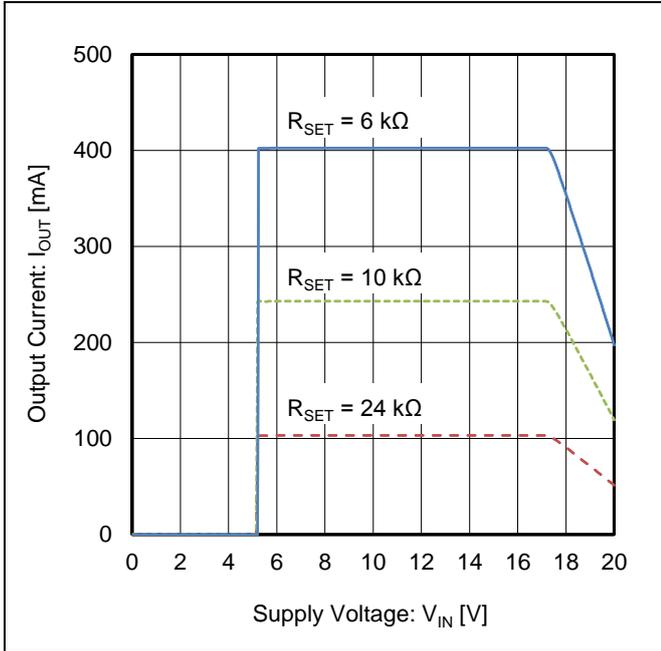


Figure 5. Output Current vs Supply Voltage

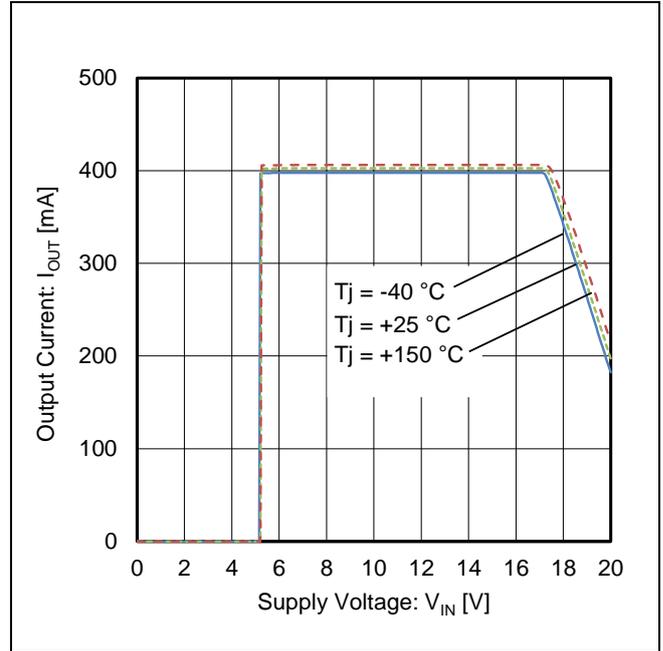


Figure 6. Output Current vs Supply Voltage

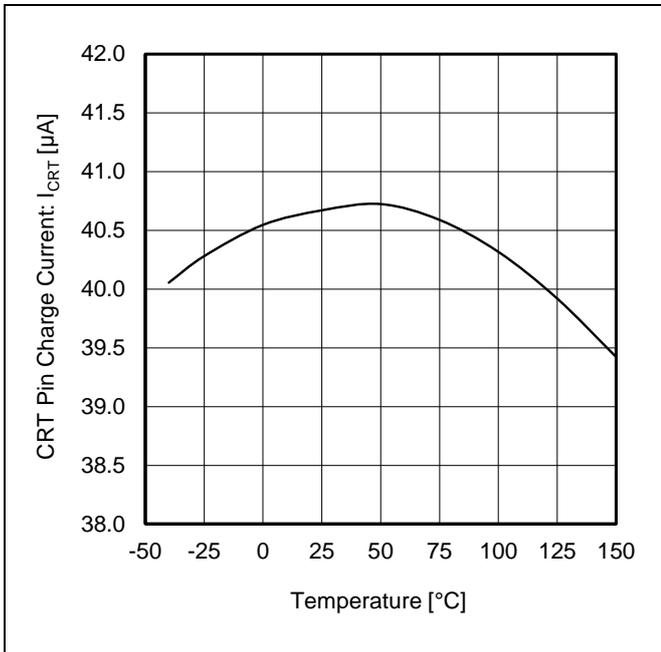


Figure 7. CRT Pin Charge Current vs Temperature

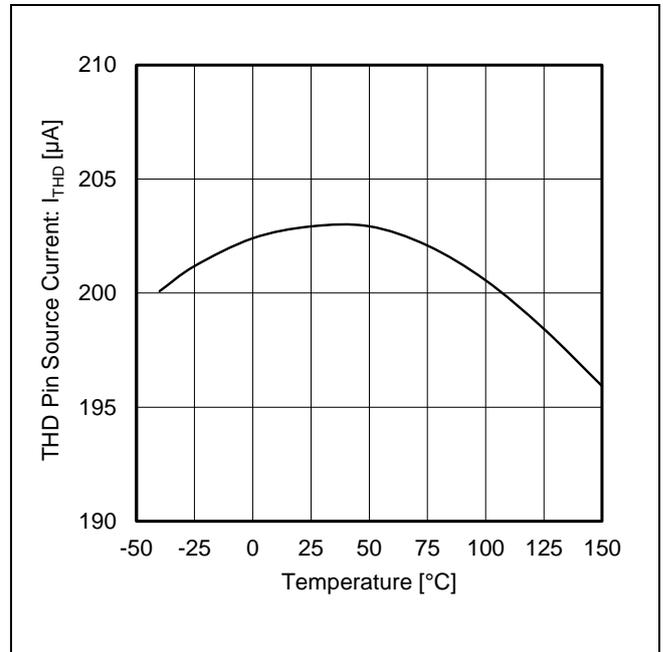


Figure 8. THD Pin Source Current vs Temperature

Typical Performance Curves (Reference Data) – continued

(Unless otherwise specified $T_j = 25\text{ }^\circ\text{C}$, $V_{IN} = 13\text{ V}$)

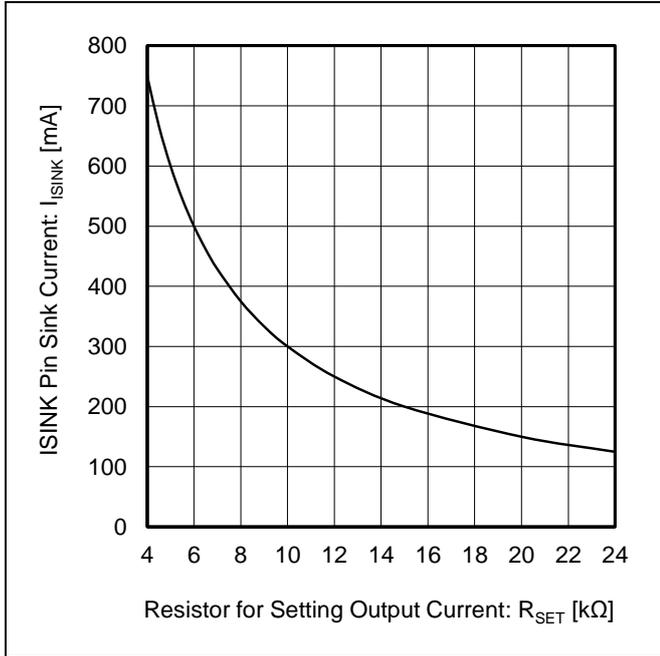


Figure 9. ISINK Pin Sink Current vs Resistor for Setting Output Current

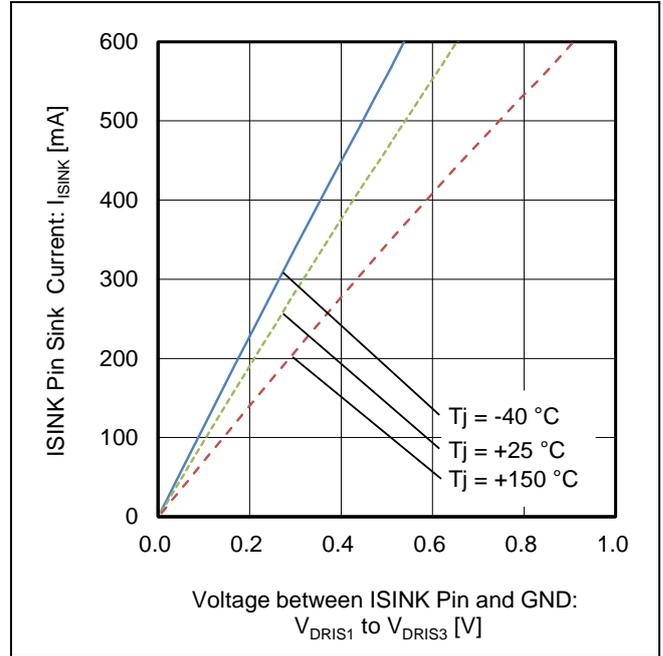


Figure 10. ISINK Pin Sink Current vs Voltage between ISINK Pin and GND

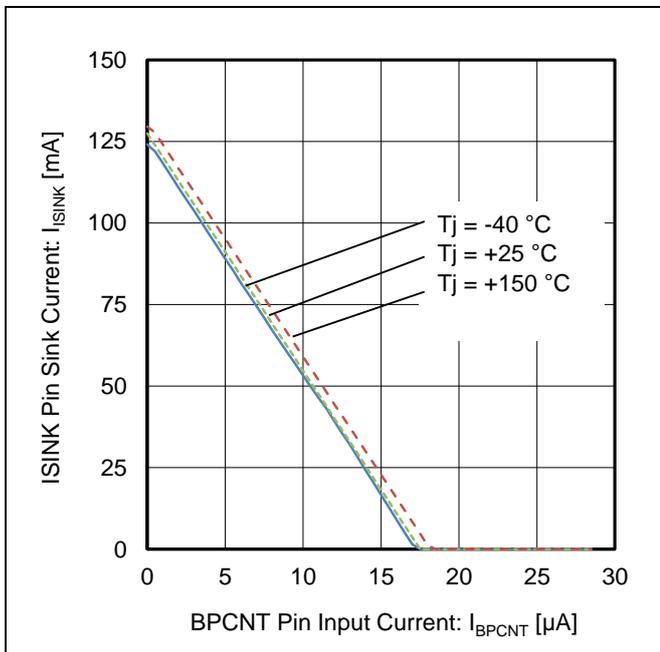
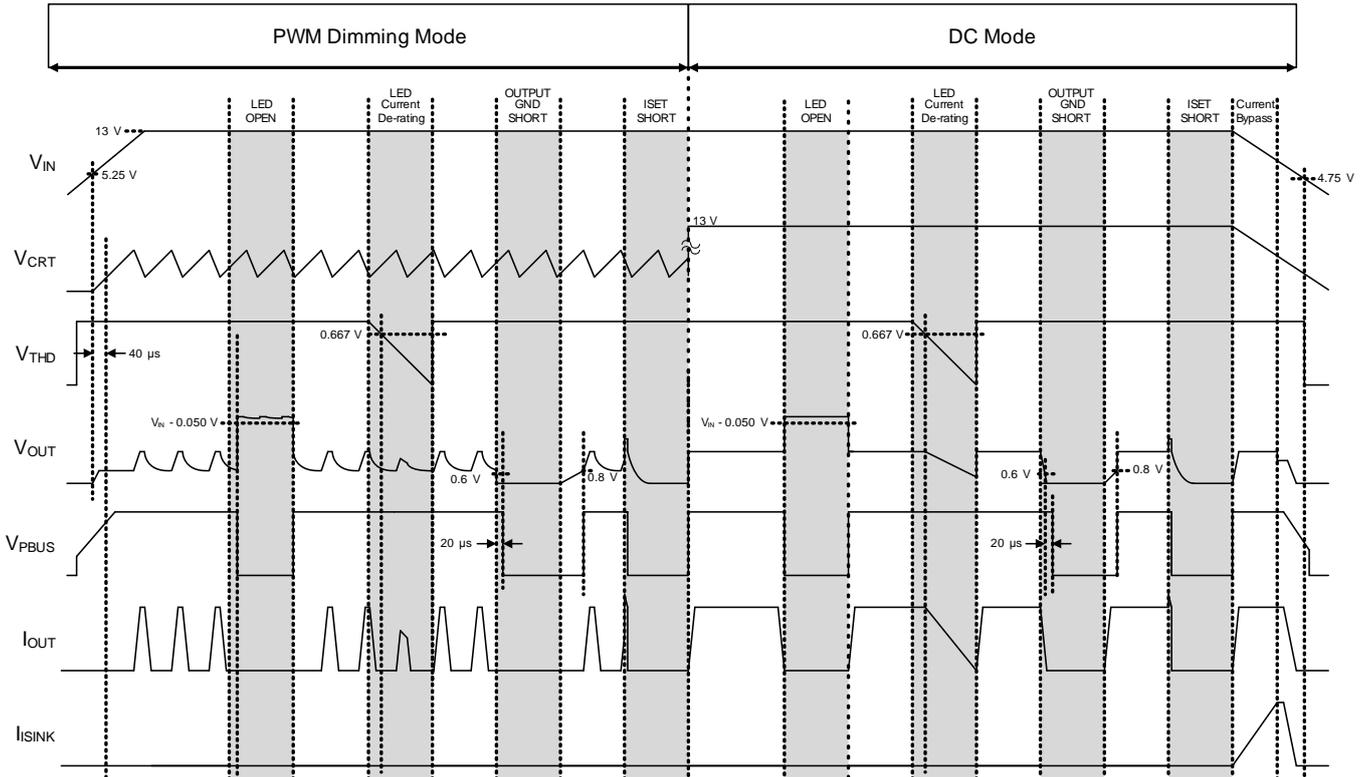


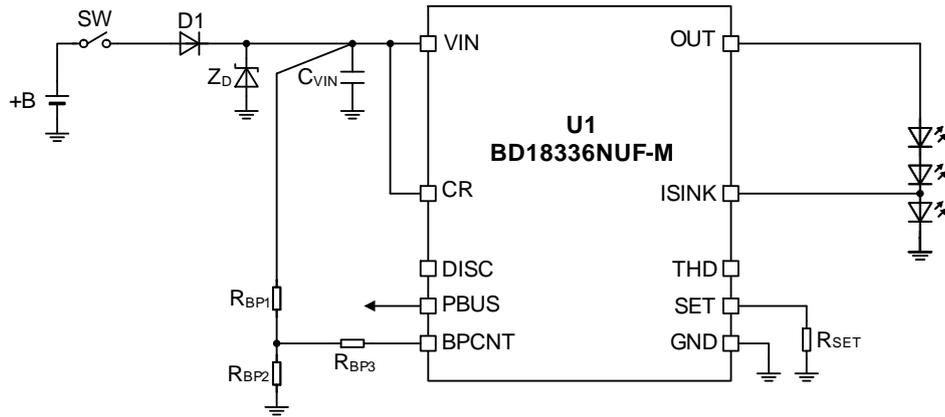
Figure 11. ISINK Pin Sink Current vs BPCNT Pin Input Current

Timing Chart



Application Examples

1. I_{OUT} = 200 mA, 3 White LEDs in Series, Unused Thermal De-rating Function

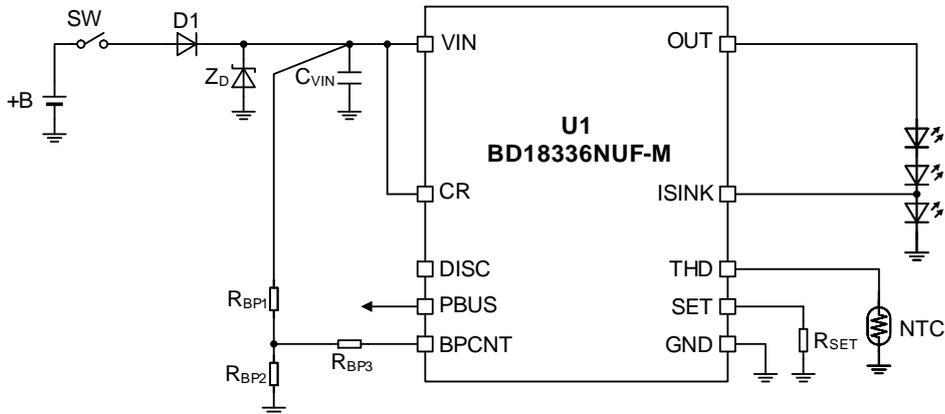


Recommended Parts List 1

Parts	No	Parts Name	Value	UNIT	Product Maker
IC	U1	BD18336NUF-M	-	-	ROHM
Diode	D1	RFN2LAM6STF	-	-	ROHM
	Z _D	TND12H-220KB00AAA0	-	-	NIPPON CHEMICON
Resistor	R _{SET}	MCR03EZPFX1202	12	kΩ	ROHM
Capacitor	C _{VIN}	GCM31CL81H105KA40	1.0	μF	murata

Caution: About Z_D, mount according to test standard of battery line.

2. I_{OUT} = 387 mA, 3 White LEDs in Series, Thermal De-rating Function



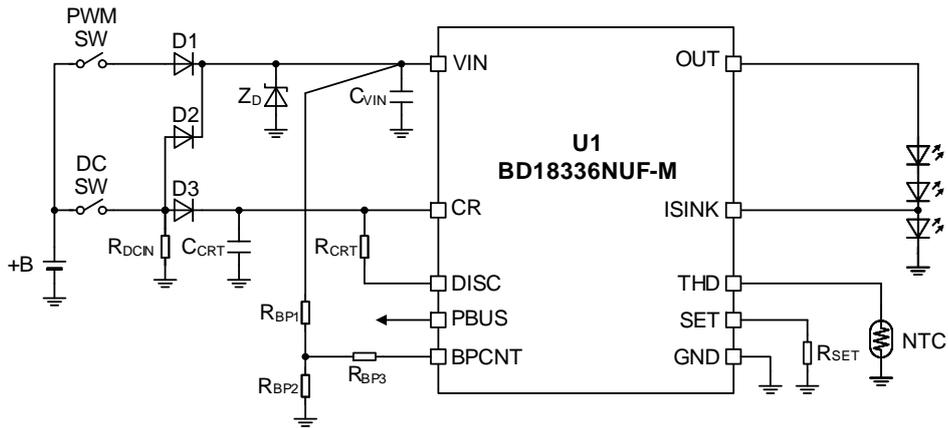
Recommended Parts List 2

Parts	No	Parts Name	Value	UNIT	Product Maker
IC	U1	BD18336NUF-M	-	-	ROHM
Diode	D1	RFN2LAM6STF	-	-	ROHM
	Z _D	TND12H-220KB00AAA0	-	-	NIPPON CHEMICON
Resistor	R _{SET}	MCR03EZPFX6201	6.2	kΩ	ROHM
Thermistor	NTC	NTCG104LH154JTDS	150	kΩ	TDK
Capacitor	C _{VIN}	GCM31CL81H105KA40	1.0	μF	murata

Caution: About Z_D, mount according to test standard of battery line.

Application Examples – continued

3. $I_{OUT} = 387 \text{ mA}$, 3 White LEDs in Series, PWM ON Duty = 10 %, Pulse Width = 0.334 ms, PWM Frequency = 300 Hz



Recommended Parts List 3

Parts	No	Parts Name	Value	UNIT	Product Maker
IC	U1	BD18336NUF-M	-	-	ROHM
Diode	D1	RFN2LAM6STF	-	-	ROHM
	D2	RFN2LAM6STF	-	-	ROHM
	D3	RFN2LAM6STF	-	-	ROHM
	Z _D	TND12H-220KB00AAA0	-	-	NIPPON CHEMICON
Resistor	R _{SET}	MCR03EZPFX6201	6.2	kΩ	ROHM
	R _{CRT}	MCR03EZPFX3601	3.6	kΩ	ROHM
	R _{DCIN}	MCR03EZPFX3902	39	kΩ	ROHM
Thermistor	NTC	NTCG104LH154JTDS	150	kΩ	TDK
Capacitor	C _{VIN}	GCM31CL81H105KA40	1.0	μF	murata
	C _{CRT}	GCM188L81H104KA42	0.1	μF	murata

Caution: About Z_D, mount according to test standard of battery line.

I/O Equivalence Circuits

No.	Pin Name	Equivalence Circuit	No.	Pin Name	Equivalence Circuit
2	BPCNT	<p>BPCNT (Pin 2)</p> <p>GND (Pin 8)</p>	6	THD	<p>THD (Pin 6)</p> <p>GND (Pin 8)</p>
3	PBUS	<p>PBUS (Pin 3)</p> <p>GND (Pin 8)</p> <p>10 Ω (Typ)</p>	7	SET	<p>SET (Pin 7)</p> <p>GND (Pin 8)</p>
4	CRT	<p>CRT (Pin 4)</p> <p>GND (Pin 8)</p>	9	ISINK	<p>VIN (Pin 1)</p> <p>ISINK (Pin 9)</p> <p>GND (Pin 8)</p>
5	DISC	<p>DISC (Pin 5)</p> <p>GND (Pin 8)</p> <p>5.2V (Typ)</p> <p>5 kΩ (Typ)</p>	10	OUT	<p>VIN (Pin 1)</p> <p>OUT (Pin 10)</p> <p>GND (Pin 8)</p>

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.
 When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

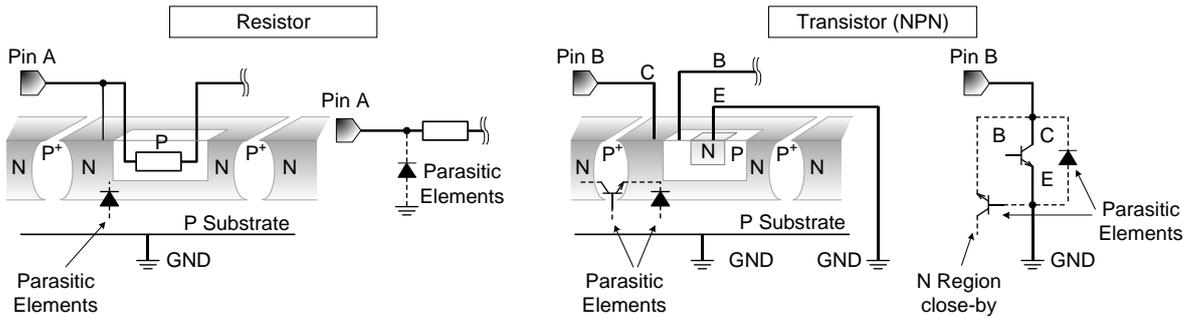


Figure 12. Example of Monolithic IC Structure

11. Ceramic Capacitor

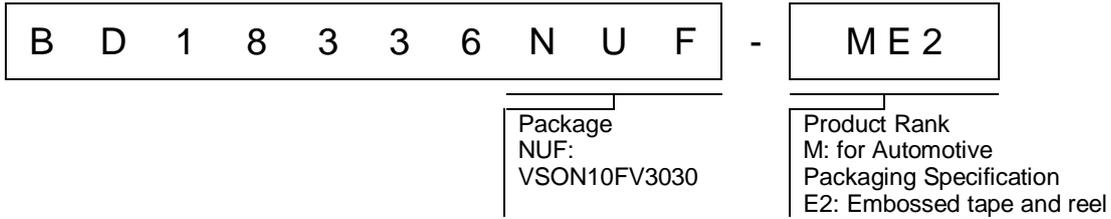
When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

12. Thermal Shutdown Circuit (TSD)

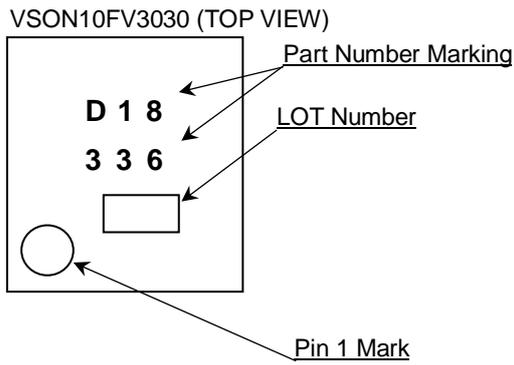
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (T_j) will rise which will activate the TSD circuit that will turn OFF power output pins. When the T_j falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

Ordering Information



Marking Diagram



Revision History

Date	Revision	Changes
25.Dec.2019	001	New Release

Notice

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1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
4. The Products are not subject to radiation-proof design.
5. Please verify and confirm characteristics of the final or mounted products in using the Products.
6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
8. Confirm that operation temperature is within the specified range described in the product specification.
9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

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